

SC10776P D01

Substitute for form 1449A/PTO INFORMATION DISCLOSURE STATEMENT BY APPLICANT (use as many sheets as necessary)				Complete if Known			
				Application Number	NO DO TITLE		
				Filing Date			
				First Named Inventor	Darrell G. Hill		
				Group Art Unit			
				Examiner Name			
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		OTHER PRIOR ART – NON PATENT LITERATURE DOCUMENTS								
Examiner Initials*	Cite No. 1	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.								
AMJ	19	H. Lin et al., "Super-Gain AlGaAs/GaAs Heterojunction Bipolar Transistors Using An Emitter Edge-Thinning Design", American Institute of Physics, appl. Phys. Letter 47(8), 15 October 1985, pages 839-841.								
VAM	20	W. Lee et al., "Effect of Emitter-Base Spacing on the current Gain of AlGaAs/GaAs Heterojunction Bipolar Transistors", IEEE Electronic Device Letters, Vol. 10, No. 5, May 1989, pages 200-202.								
10.41	21	Wolf, S., "Silicon Processing for the VLSI Era, Volume 2", Process Integration, Sunset Beach, CA, 1990, pages 486-488.	•							
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Examiner Signature	The	or A	Mar	ulsla	9	Date Considered	8-30-04	

EXAMINER: Initial if reference considered, whether or not clation is in conformance with MPEP 809. Draw line through citation, if not in conformance and not constructed copy of this form with next communication to applicant.

^{*}Unique citation designation number. * Applicant is to place a check mark here if English Language Translation is attached.